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FDB045AN08A0_F085 N-Channel PowerTrench[®] MOSFET FAIRCHILD SEMICONDUCTOR® June 2010 FDB045AN08A0_F085 N-Channel PowerTrench[®] MOSFET **75V, 80A, 4.5m**Ω **Features Applications** r_{DS(ON)} = 3.9mΩ (Typ.), V_{GS} = 10V, I_D = 80A • 42V Automotive Load Control Q_q(tot) = 92nC (Typ.), V_{GS} = 10V • Starter / Alternator Systems Low Miller Charge · Electronic Power Steering Systems Low Q_{RR} Body Diode · Electronic Valve Train Systems • UIS Capability (Single Pulse and Repetitive Pulse) · DC-DC converters and Off-line UPS Qualified to AEC Q101 · Distributed Power Architectures and VRMs · RoHS Compliant · Primary Switch for 24V and 48V systems Formerly developmental type 82684 GATE DRAIN SOURCE (FLANGE) TO-263AB FDB SERIES MOSFET Maximum Ratings T_C = 25°C unless otherwise noted Symbol Parameter Ratings Units V_{DSS} Drain to Source Voltage 75 V V_{GS} Gate to Source Voltage ±20 V Drain Current Continuous ($T_C < 137^{\circ}C$, $V_{GS} = 10V$) 90 Α I_D Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta JA} = 43^{\circ}C/W$) А 19 Figure 4 А Pulsed E_{AS} Single Pulse Avalanche Energy (Note 1) 600 mJ Power dissipation 310 W P_D Derate above 25°C 2.0 W/ºC T_J, T_{STG} Operating and Storage Temperature -55 to 175 °C **Thermal Characteristics** п Thormal Posistance Junction to Case TO 262 0 10 °C/M

Π _θ JC	Thermal Resistance Junction to Case TO-263	0.48	-C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263 (Note 2)	62	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, 1in ² copper pad area	43	°C/W

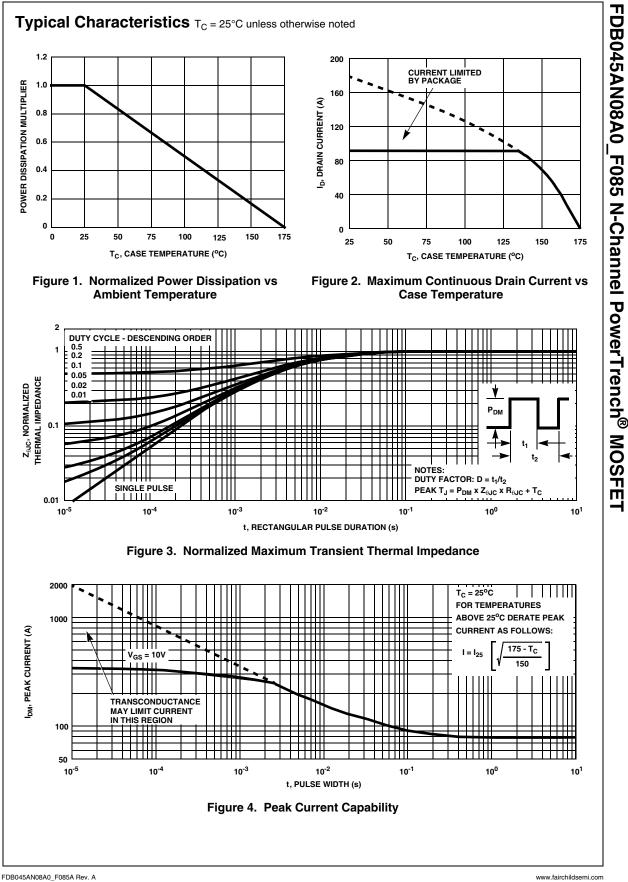
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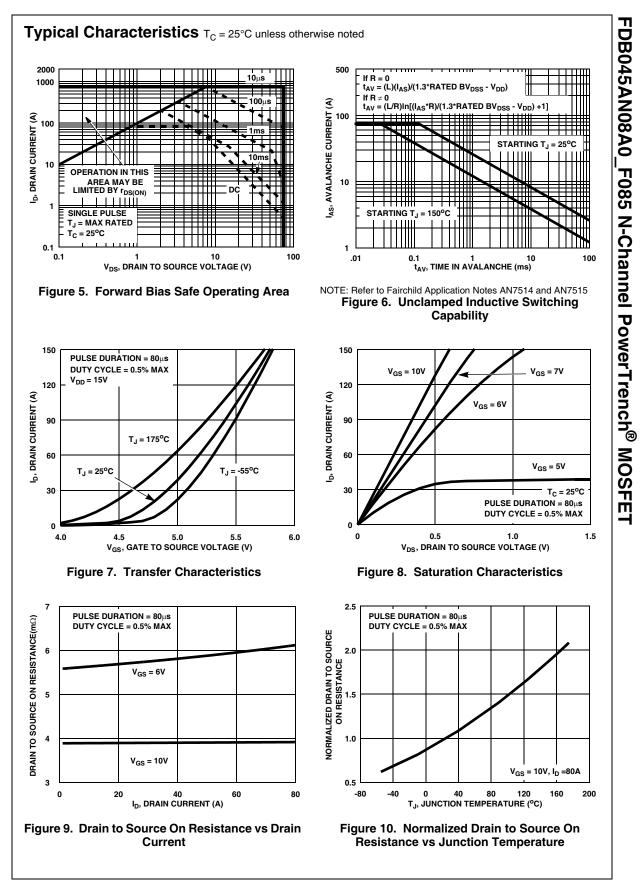
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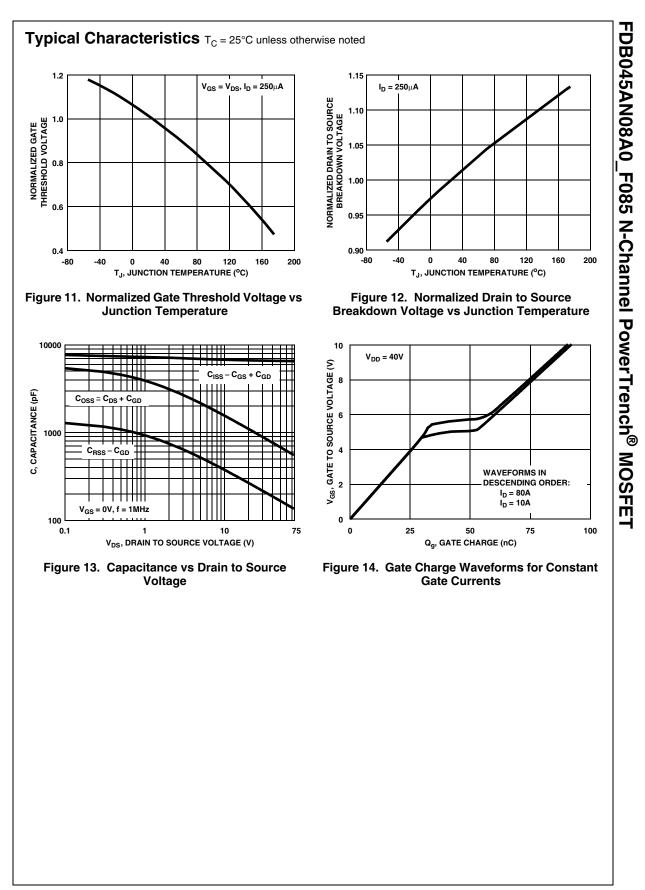
	Device Marking Device F		Package	Package Reel Size		Width	Quantity	
	FDB045AN08A0 FDB045AN08A0_F085			330mm	24mm		800 units	
Electric	al Chai	racteristics T _C = 25°C	Cunless otherwis	e noted				
Symbol		Parameter		Conditions	Min	Тур	Max	Units
Off Chara	acteristic	S						
B _{VDSS}	Drain to	Source Breakdown Voltage	I _D = 250μA, \	$V_{GS} = 0V$	75	-	-	V
	Zero Gate Voltage Drain Current		$V_{DS} = 60V$			-	1	
IDSS			$V_{GS} = 0V$	$T_{C} = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to S	Gate to Source Leakage Current		$V_{GS} = \pm 20V$		-	±100	nA
On Chara	cteristic	S						
V _{GS(TH)}	Gate to S	Source Threshold Voltage	$V_{GS} = V_{DS}, I_{I}$	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		-	4	V
uu(111)			$I_{\rm D} = 80$ A, $V_{\rm GS}$		-	0.0039	0.0045	
	Drain to (Source On Registeres		$I_D = 37A, V_{GS} = 6V$ $I_D = 80A, V_{GS} = 10V,$		0.0056	0.0084	0
r _{DS(ON)}		Source On Resistance	I _D = 80A, V _G			0.008	0.011	Ω
			T _J = 175 ^o C		-	0.000	, 0.011	
Dynamic	Charact	eristics						
C _{ISS}	Input Ca	pacitance			-	6600	-	pF
C _{OSS}	Output C	apacitance	— V _{DS} = 25V, V — f = 1MHz	$V_{\rm DS} = 25V, V_{\rm GS} = 0V,$		1000	-	pF
C _{RSS}	Reverse	Transfer Capacitance			-	240	-	pF
Q _{g(TOT)}	Total Ga	te Charge at 10V	$V_{GS} = 0V$ to T	10V		92	138	nC
Q _{g(TH)}	Threshol	d Gate Charge	V _{GS} = 0V to 2	$2V V_{DD} = 40V$	-	11	17	nC
Q _{gs}	Gate to S	Source Gate Charge		I _D = 80A		27	-	nC
Q _{gs2}	Gate Cha	arge Threshold to Plateau		l _g = 1.0mA	-	16	-	nC
Q _{gd}	Gate to D	Drain "Miller" Charge	<u> </u>			21	-	nC
Switchin	a Charac	cteristics (V _{GS} = 10V)						
t _{ON}	Turn-On				-	-	160	ns
t _{d(ON)}	Turn-On	Delay Time	_		-	18	-	ns
t _r	Rise Tim		V _{DD} = 40V, I _I	- = 80A	-	88	-	ns
	Turn-Off	Delay Time	$V_{GS} = 10V, F$		-	40	-	ns
	Fall Time				-	45	-	ns
t _{d(OFF)} t _f		Time			-	-	128	ns
t _f	Turn-Off							
t _f t _{OFF}			<u> </u>					
t _f t _{OFF} Drain-So	urce Dio	de Characteristics	I _{SD} = 80A		-	-	1.25	V
t _f t _{OFF}	urce Dio		I _{SD} = 80A I _{SD} = 40A		-	-	1.25 1.0	V V
t _f t _{OFF} Drain-So	urce Dio Source to	de Characteristics	$I_{SD} = 40A$	_{SD} /dt = 100A/μs				

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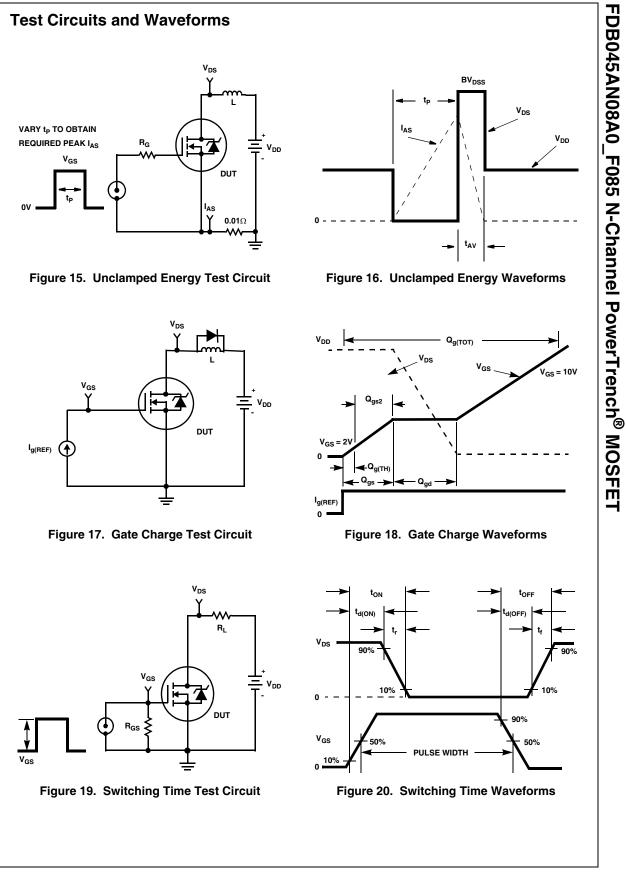


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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\Theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{0,JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

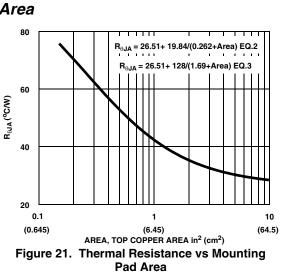
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\Theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
 (EQ.2)

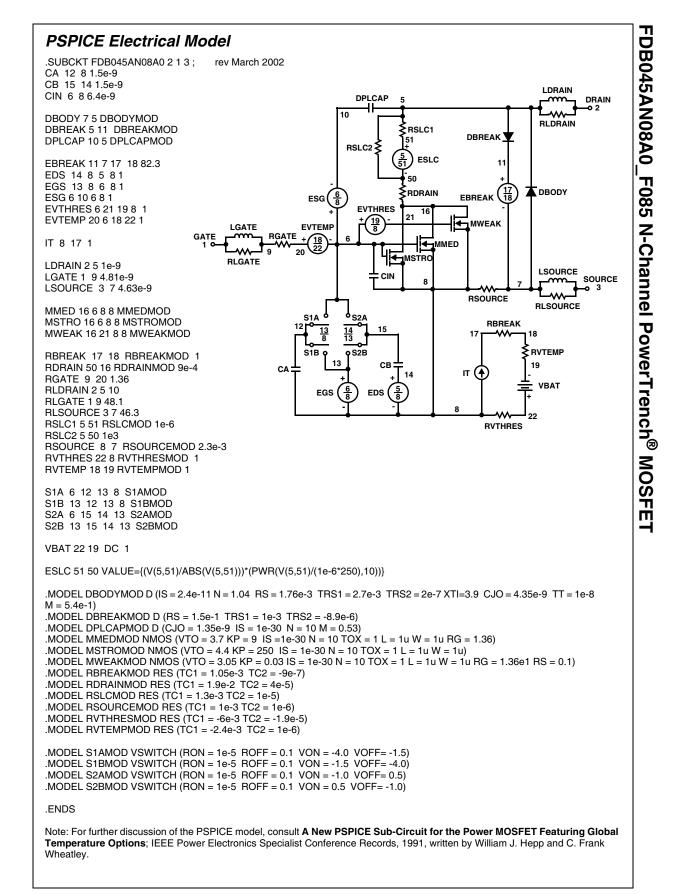
Area in Inches Squared

$$R_{\theta,JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
 (EQ. 3)

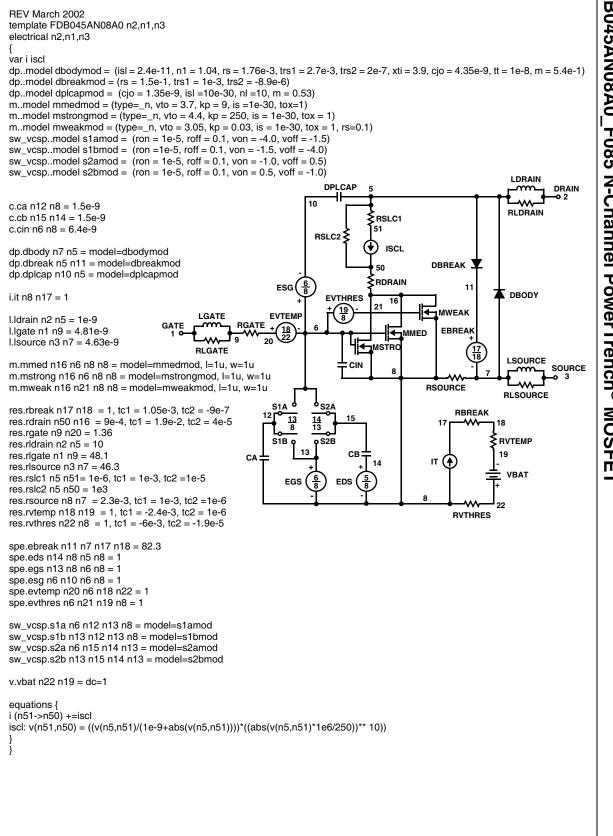
Area in Centimeter Squared



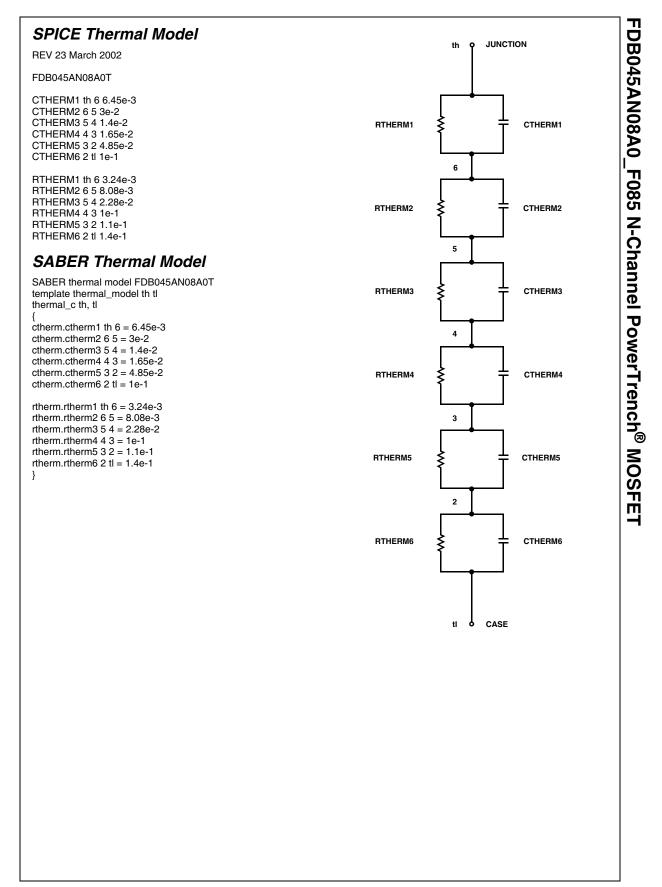
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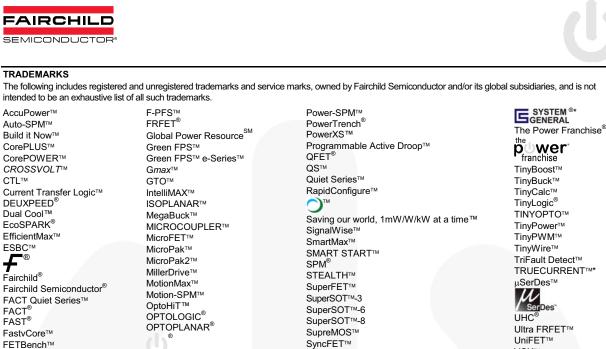


SABER Electrical Model



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